NSN 5961-00-088-9350



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-088-9350 **Inclosure Material:** Metal **Overall Length:** 0.390 inches **Overall Diameter:** 0.370 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.250 inches **Thread Size:** 0.164 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Specification Data:

80131-release3362 professional/industrial association specification

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NSN 5961-00-088-9350

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

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